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54ACQQ373 • 54ACTQ373 Quiet Series

Octal Transparent Latch with TRI-STATE Outputs

National Semiconductor

54ACQ373 • 54ACTQ373 Quiet Series Octal Transparent Latch with TRI-STATE® Outputs

General Description

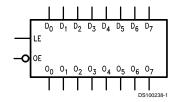
The 'ACQ/'ACTQ373 consists of eight latches with TRI-STATE outputs for bus organized system applications. The latches appear transparent to the data when Latch Enable (LE) is HIGH. When LE is low, the data satisfying the input timing requirements is latched. Data appears on the bus when the Output Enable (OE) is LOW. When OE is HIGH, the bus output is in the high impedance state.

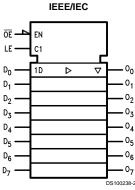
The 'ACQ/'ACTQ373 utilizes NSC Quiet Series technology to guarantee quiet output switching and improve dynamic threshold performance. FACT Quiet SeriesTM features GTOTM output control and undershoot corrector in addition to a split ground bus for superior performance.

Features

- I_{CC} and I_{OZ} reduced by 50%
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch up immunity
- Eight latches in a single package
- TRI-STATE outputs drive bus lines or buffer memory address registers
- Outputs source/sink 24 mA
- Faster prop delays than the standard 'AC/'ACT373
- 4 kV minimum ESD immunity ('ACQ)
- Standard Military Drawing (SMD)
 - 'ACTQ373: 5962-92188

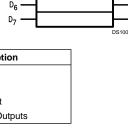
Logic Symbols



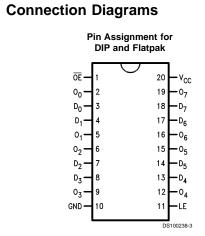


Pin Names	Description
D ₀ -D ₇	Data Inputs
LE	Latch Enable Input
OE	Output Enable Input
0 ₀ –0 ₇	TRI-STATE Latch Outputs

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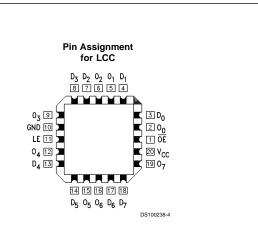
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Functional Description

The 'ACQ/'ACTQ373 contains eight D-type latches with TRI-STATE standard outputs. When the Latch Enable (LE) input is HIGH, data on the D_n inputs enters the latches. In this condition the latches are transparent, i.e., a latch output will change state each time its D input changes. When LE is LOW, the latches store the information that was present on the D inputs a setup time preceding the HIGH-to-LOW transition of LE. The TRI-STATE standard outputs are controlled by the Output Enable (\overline{OE}) input. When \overline{OE} is LOW, the standard outputs are in the 2-state mode. When \overline{OE} is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.



Truth Table

	Inputs				
LE	ŌE	D _n	On		
Х	Н	Х	Z		
Н	L	L	L		
Н	L	Н	н		
L	L	Х	Oo		

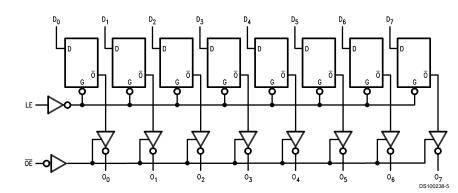
H = HIGH Voltage Level L = LOW Voltage Level

Z = High Impedance

X = Immaterial

 O_0 = Previous O_0 before HIGH to Low transition of Latch Enable

Logic Diagram



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})

 $V_I = V_{CC} + 0.5V$

DC Input Voltage (V_I)

 $V_{\rm O} = V_{\rm CC} + 0.5 V$

DC Output Voltage (V_O)

DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})

Storage Temperature (T_{STG}) DC Latchup Source or Sink Current

Junction Temperature (T_{J})

CDIP

 $V_{1} = -0.5V$

 $V_{O} = -0.5V$

DC Output Source or Sink Current (I_O)

DC Input Diode Current (I_{IK})

DC Output Diode Current (I_{OK})

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

-0.5V to +7.0V

–0.5V to V $_{\rm CC}$ + 0.5V

–0.5V to V_{CC} + 0.5V

–20 mA

+20 mA

–20 mA

+20 mA

±50 mA

±50 mA -65°C to +150°C

±300 mA

175°C

Recommended Operating Conditions

Supply (1) = 0	
Supply Voltage (V _{CC})	
'ACQ	2.0V to 6.0V
'ACTQ	4.5V to 5.5V
Input Voltage (V _I)	0V to V_{CC}
Output Voltage (V _O)	0V to V_{CC}
Operating Temperature (T _A)	
54ACQ/ACTQ	-55°C to +125°C
Minimum Input Edge Rate ΔV/Δt	
'ACQ Devices	
V_{IN} from 30% to 70% of V_{CC}	
V _{CC} @ 3.0V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate $\Delta V / \Delta t$	
'ACTQ Devices	
V _{IN} from 0.8V to 2.0V	105 14
V _{CC} @ 4.5V, 5.5V	125 mV/ns
Note: All commercial packaging is not recommen- ing greater than 2000 temperature cycles from –	
Note 1: Absolute maximum ratings are those val	
to the device may occur. The databook specificati	

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT® circuits outside databook specifications.

DC Characteristics for 'ACQ Family Devices

			54ACQ		
Symbol	Parameter	V _{cc}	T _A =	Units	Conditions
		(V)	-55°C to +125°C		
			Guaranteed Limits	1	
VIH	Minimum High Level	3.0	2.1		V _{OUT} = 0.1V
	Input Voltage	4.5	3.15	V	or V _{CC} – 0.1V
		5.5	3.85		
VIL	Maximum Low Level	3.0	0.9		V _{OUT} = 0.1V
	Input Voltage	4.5	1.35	V	or V _{CC} – 0.1V
		5.5	1.65		
V _{он}	Minimum High Level	3.0	2.9		I _{OUT} = -50 μA
	Output Voltage	4.5	4.4	V	
		5.5	5.4		
					(Note 2)
					$V_{IN} = V_{IL} \text{ or } V_{IH}$
		3.0	2.4		I _{он} = –12 mA
		4.5	3.7	V	I _{ОН} = –24 mA
		5.5	4.7		I _{он} = –24 mA
V _{OL}	Maximum Low Level	3.0	0.1		Ι _{ΟUT} = 50 μΑ
	Output Voltage	4.5	0.1	V	
		5.5	0.1		
					(Note 2)
					$V_{IN} = V_{IL} \text{ or } V_{IH}$
		3.0	0.50		I _{OL} = 12 mA
		4.5	0.50	V	I _{OL} = 24 mA
		5.5	0.50		I _{OL} = 24 mA
I _{IN}	Maximum Input	5.5	±1.0	μΑ	$V_{I} = V_{CC}, GND$
	Leakage Current				(Note 4)

			54ACQ		
Symbol	Parameter	V _{cc}	T _A =	Units	Conditions
		(V)	–55°C to +125°C		
			Guaranteed Limits		
I _{OLD}	Minimum Dynamic (Note 3)	5.5	50	mA	V _{OLD} = 1.65V Max
I _{OHD}	Output Current	5.5	-50	mA	V _{OHD} = 3.85V Min
I _{cc}	Maximum Quiescent	5.5	80.0	μA	$V_{IN} = V_{CC}$
	Supply Current				or GND (Note 4)
I _{oz}	Maximum TRI-STATE				$V_{I}(OE) = V_{IL}, V_{IH}$
	Leakage Current	5.5	±5.0	μA	$V_{I} = V_{CC}, GND$
					$V_{O} = V_{CC}, GND$
V _{OLP}	Quiet Output	5.0	1.5	V	
	Maximum Dynamic V _{OL}				(Notes 5, 6)
V _{OLV}	Quiet Output	5.0	-1.2	V	
	Maximum Dynamic V _{OL}				(Notes 5, 6)

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I_{IN} and I_{CC} @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V_{CC}.

I_{CC} for 54ACQ @ 25°C is identical to 74ACQ @ 25°C.

Note 5: Plastic DIP package.

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Note 6: Max number of outputs defined as (n). Data inputs are driven 0V to 5V. One output @ GND.

Note 7: Max number of data inputs (n) switching. (n-1) inputs switching 0V to 5V ('ACQ). Input-under-test switching: 5V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

			54ACTQ		
Symbol	Parameter	V _{cc}	T _A =	Units	Conditions
		(V)	–55°C to +125°C		
			Guaranteed Limits	1	
V _{IH}	Minimum High Level	4.5	2.0	V	V _{OUT} = 0.1V
	Input Voltage	5.5	2.0		or $V_{CC} - 0.1V$
V _{IL}	Maximum Low Level	4.5	0.8	V	V _{OUT} = 0.1V
	Input Voltage	5.5	0.8		or V _{CC} – 0.1V
V _{OH}	Minimum High Level	4.5	4.4	V	I _{OUT} = -50 μA
	Output Voltage	5.5	5.4		
					(Note 8) V _{IN} = V _{IL} or V _{IH}
		4.5	3.70	V	I _{OH} = -24 mA
		5.5	4.70		I _{OH} = -24 mA
V _{OL}	Maximum Low Level	4.5	0.1	V	Ι _{ΟUT} = 50 μΑ
	Output Voltage	5.5	0.1		
					(Note 8) V _{IN} = V _{IL} or V _{IH}
		4.5	0.50	V	I _{OL} = 24 mA
		5.5	0.50		I _{OL} = 24 mA
I _{IN}	Maximum Input	5.5	±1.0	μA	$V_{I} = V_{CC}, GND$
	Leakage Current				
l _{oz}	Maximum TRI-STATE	5.5	±5.0	μA	$V_{I} = V_{IL}, V_{IH}$
	Leakage Current				$V_{O} = V_{CC}, GND$

DC Characteristics for 'ACTQ Family Devices

			54ACTQ		
Symbol	Parameter	V _{cc}	T _A =	Units	Conditions
		(V)	–55°C to +125°C		
			Guaranteed Limits		
I _{CCT}	Maximum	5.5	1.6	mA	$V_{I} = V_{CC} - 2.1V$
	I _{CC} /Input				
I _{OLD}	Minimum Dynamic	5.5	50	mA	V _{OLD} = 1.65V Max
I _{OHD}	Output Current	5.5	-50	mA	V _{OHD} = 3.85V Min
	(Note 9)				
I _{cc}	Maximum Quiescent	5.5	80.0	μA	$V_{IN} = V_{CC}$
	Supply Current				or GND (Note 10)
V _{OLP}	Quiet Output	5.0	1.5	V	
	Maximum Dynamic V _{OL}				(Notes 11, 12)
V _{OLV}	Quiet Output	5.0	-1.2	V	
	Minimum Dynamic Vol				(Notes 11, 12)

Note 8: All outputs loaded; thresholds on input associated with output under test.

Note 9: Maximum test duration 2.0 ms, one output loaded at a time.

Note 10: I_{CC} for 54ACTQ @ 25°C is identical to 74ACTQ @ 25°C.

Note 11: Plastic DIP package.

Note 12: Max number of outputs defined as (n). Data inputs are driven 0V to 3V. One output @ GND.

AC Electrical Characteristics

		54ACQ					
Symbol	Parameter	V _{cc} (V)	to +	T _A = -55°C to +125°C			
		(Note 13) C _L = 50 pF		C _L = 50 pF Min Max			-
	Dranagation Dalay	2.2		15.0			
t _{PHL} , t _{PLH}	Propagation Delay	3.3	1.0		ns		
	D _n to O _n	5.0	1.0	9.5			
t _{PHL} , t _{PLH}	Propagation Delay	3.3	1.0	16.0	ns		
	LE to O _n	5.0	1.0	9.5			
t _{PZL} , t _{PZH}	Output Enable Time	3.3	1.0	14.5	ns		
		5.0	1.0	10.5			
t _{PHZ} , t _{PLZ}	Output Disable Time	3.3	1.0	12.0	ns		
		5.0	1.0	10.5			

Note 13: Voltage Range 5.0 is 5.0V ±0.5V. Voltage Range 3.3 is 3.3V ±0.3V.

AC Operating Requirements

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			54ACQ	
Symbol	Parameter	V _{cc} (V)	T _A = −55°C to +125°C	Units
		(Note 14)	C _L = 50 pF	
			Guaranteed Minimum	
t _s	Setup Time, HIGH or LOW	3.3	3.0	ns
	D _n to LE	5.0	3.0	
t _h	Hold Time, HIGH or LOW	3.3	1.5	ns
	D _n to LE	5.0	1,5	
t _w	LE Pulse Width, HIGH	3.3	5.0	ns
		5.0	5.0	

Note 14: Voltage Range 5.0 is 5.0V ± 0.5 V.

Voltage Range 3.3 is 3.3V ±0.3V.

AC Electrical Characteristics

Symbol	Parameter	V _{cc} (V) (Note 15)	T _A = to +	CTQ -55°C 125°C 50 pF	Units
			Min	Max	
t _{PHL} , t _{PLH}	Propagation Delay	5.0	1.5	10.5	ns
	D _n to O _n				
t _{PHL} , t _{PLH}	Propagation Delay	5.0	1.5	11.5	ns
	LE to O _n				
t _{PZL} , t _{PZH}	Output Enable Time	5.0	1.5	11.0	ns
t _{PHZ} , t _{PLZ}	Output Disable Time	5.0	1.5	10.5	ns

Note 15: Voltage Range 5.0 is 5.0V ±0.5V.

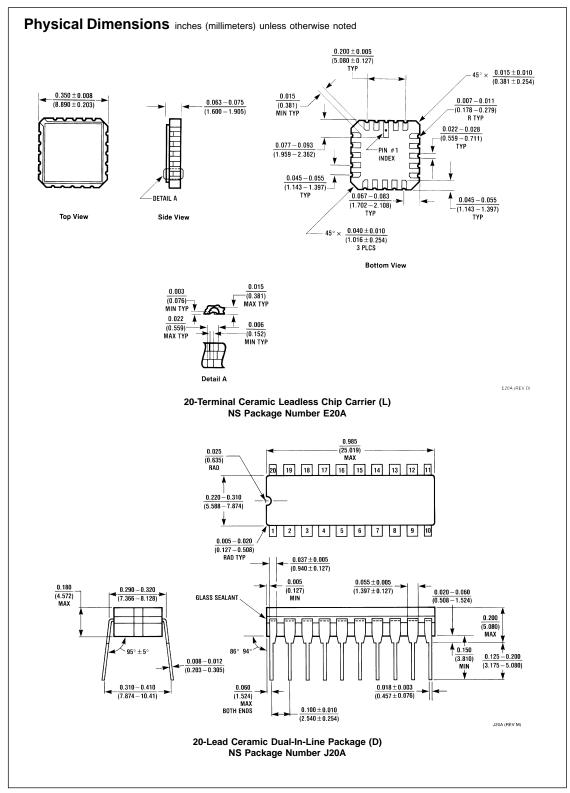
AC Operating Requirements

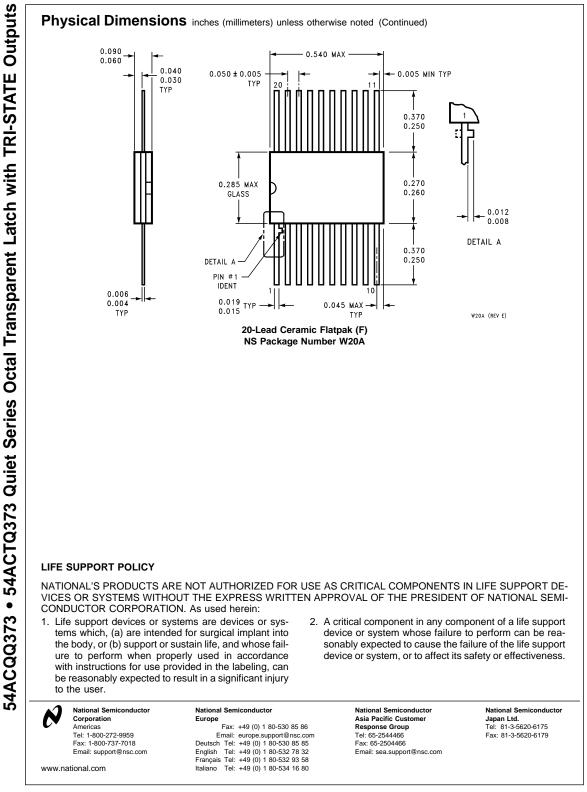
Symbol	Parameter	V _{cc} (V) (Note 16)	$54ACTQ$ $T_{A} = -55°C$ to +125°C $C_{L} = 50 \text{ pF}$ Guaranteed Minimum	Units
t _s	Setup Time, HIGH or LOW	5.0	3.5	ns
	D _n to LE			
t _h	Hold Time, HIGH or LOW	5.0	1.5	ns
	D _n to LE			
t _w	LE Pulse Width, HIGH	5.0	5.0	ns

Note 16: Voltage Range 5.0 is 5.0V ±0.5V

Capacitance

Symbol	Parameter	Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation	44.0	pF	$V_{\rm CC} = 5.0 V$
	Capacitance			





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